

# Switching diode

## 1N4531 / 1N4148 / 1N4150 / 1N4448

\*This product is available only outside of Japan.

● **Application**

High-speed switching

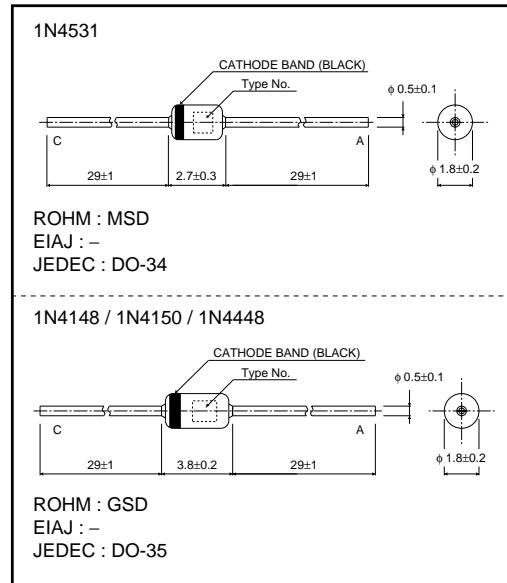
● **Features**

- 1) Glass sealed envelope. (MSD, GSD)
- 2) High speed.
- 3) High reliability.

● **Construction**

Silicon epitaxial planar

● **External dimensions (Units : mm)**



● **Absolute maximum ratings (Ta = 25°C)**

| Type   | V <sub>RM</sub> (V) | V <sub>R</sub> (V) | I <sub>FM</sub> (mA) | I <sub>o</sub> (mA) | I <sub>F</sub> (mA) | I <sub>FSM</sub> 1μs (A) | P (mW) | T <sub>j</sub> (°C) | Topr (°C) | Tstg (°C) |
|--------|---------------------|--------------------|----------------------|---------------------|---------------------|--------------------------|--------|---------------------|-----------|-----------|
| 1N4531 | 100                 | 75                 | 450                  | 150                 | 200                 | 2                        | 500    | 200                 | -65~+200  | -65~+200  |
| 1N4148 | 100                 | 75                 | 450                  | 150                 | 200                 | 2                        | 500    | 200                 | -65~+200  | -65~+200  |
| 1N4150 | 50                  | 50                 | 600                  | 200                 | 250                 | 4                        | 500    | 200                 | -65~+200  | -65~+200  |
| 1N4448 | 100                 | 75                 | 450                  | 150                 | 200                 | 2                        | 500    | 200                 | -65~+200  | -65~+200  |

● **Electrical characteristics (Ta = 25°C)**

| Type   | V <sub>F</sub> (V) |          |       |       |       |        |        |        |        |         |         |         |       | BV (V) Min. |                    | I <sub>r</sub> (μA) Max. |                    | C <sub>r</sub> (pF) | t <sub>r</sub> (ns) |                     |
|--------|--------------------|----------|-------|-------|-------|--------|--------|--------|--------|---------|---------|---------|-------|-------------|--------------------|--------------------------|--------------------|---------------------|---------------------|---------------------|
|        | @ 0.1mA            | @ 0.25mA | @ 1mA | @ 2mA | @ 5mA | @ 10mA | @ 20mA | @ 30mA | @ 50mA | @ 100mA | @ 200mA | @ 250mA | @ 5μA | @ 100μA     | @ 25°C             |                          | @ 150°C            |                     |                     |                     |
|        |                    |          |       |       |       |        |        |        |        |         |         |         |       |             | V <sub>R</sub> (V) | I <sub>r</sub> (μA)      | V <sub>R</sub> (V) |                     |                     | I <sub>r</sub> (μA) |
| 1N4531 | /                  | /        | /     | /     | /     | 1.0    | /      | /      | /      | /       | /       | /       | 75    | 100         | 0.025<br>5.0       | 20<br>75                 | 50.0               | 20                  | 4                   | 4                   |
| 1N4148 | /                  | /        | /     | /     | /     | 1.0    | /      | /      | /      | /       | /       | /       | 75    | 100         | 0.025<br>5.0       | 20<br>75                 | 50.0               | 20                  | 4                   | 4                   |
| 1N4150 | /                  | /        | 0.54  | /     | /     | 0.66   | /      | /      | 0.76   | 0.82    | 0.87    | /       | -     | 50          | 0.1                | 50                       | 100.0              | 50                  | 2.5                 | 4                   |
| 1N4448 | /                  | /        | 0.62  | /     | 0.62  | 0.74   | /      | /      | 0.86   | 0.92    | 1.0     | /       | -     | 100         | 0.025<br>5.0       | 20<br>75                 | 50.0               | 20                  | 4                   | 4                   |

The upper figure is the minimum V<sub>F</sub> and the lower figure is the maximum V<sub>F</sub> value.



Diodes

● Electrical characteristic curves (Ta = 25°C)

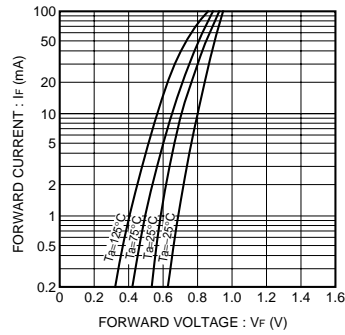


Fig. 1 Forward characteristics

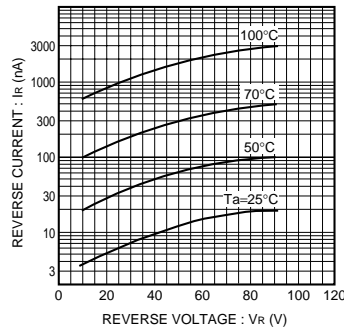


Fig. 2 Reverse characteristics

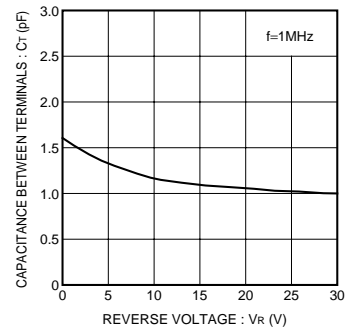


Fig. 3 Capacitance between terminals characteristics

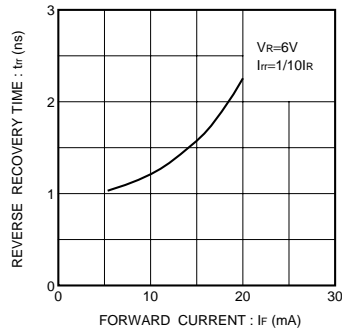


Fig. 4 Reverse recovery time characteristics

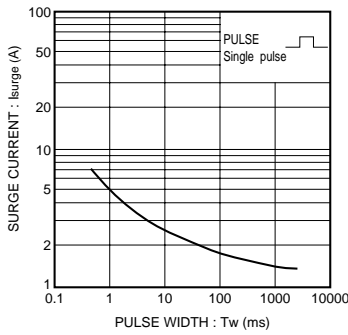


Fig. 5 Surge current characteristics

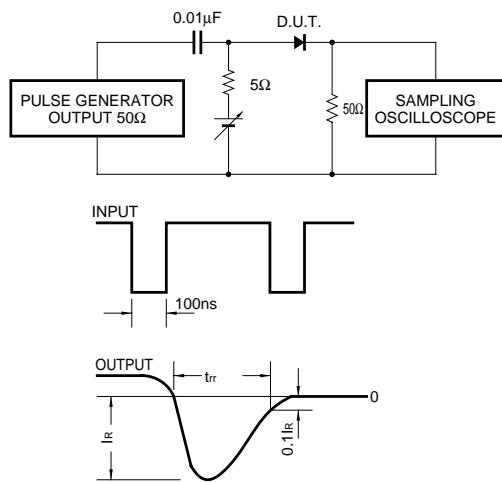


Fig. 6 Reverse recovery time ( $t_{rr}$ ) measurement circuit

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